

60A 300V Fast recovery diode

1 Description

S60A, 300V Ultrafast Diodes They have a low forward voltage drop and are of planar, silicon nitride passivated, ion-implanted, epitaxial construction. These devices are intended for use as energy steering/clamping diodes and rectifiers in a variety of switching power supplies and other power switching applications. Their low stored charge and ultrafast recovery with soft recovery characteristics minimizes ringing and electrical noise in many power switching circuits, thus reducing power loss in the switching transistor

2 Features

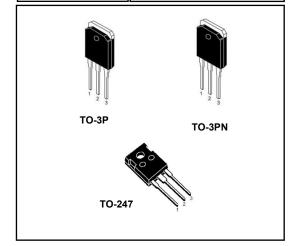
- Low power loss,
- high efficiency Low forward voltage,
- high current capability High surge capacity
- Super fast recovery times
- high voltage

3 Applications

- Switching Power Supply
- Power Switching Circuits
- Inverter power supply

4 Electrical Characteristics

$V_{BR} = 300V$ $V_{F}(single) = 1.15V$ $I_{F(AV)}(single) = 30A$



4.1 Absolute Maximum Ratings (Tc=25 °C,unless otherwise noted)

PARAMETER		SYMBOL	VALUE	UNIT
Peak Repetitive Reverse Voltage		V _{RRM}	300	V
Working Peak Reverse Voltage		V_{RWM}	300	V
DC Blocking Voltage		V _R	300	V
Average Rectified Forward Current(single)		I _{F(AV)}	30	Α
Average Rectified Forward Current(double)			60	Α
Repetitive Peak Surge Current(single)		I _{FRM}	40	Α
Nonrepetitive Peak Surge Current(single) tp=8.3ms		I _{FSM}	350	Α
Avalanche Energy(single) L=1mH		E _{AS}	80	mJ
Operating Junction Temperature Range		Tj	- 55∼150	$^{\circ}$
Storage Temperature Range		T _{stg}	<i>-</i> 55∼150	$^{\circ}$

4.2 Thermal Characteristics

PARAMETER	SYMBOL	VALUE		UNIT
PARAWETER		TO-3P/3PN	TO-247	UNII
Thermal Resistance, Junction to Case-sink	R _{thJC}	0.75	0.65	°C/W



4.3 Electrical Characteristics

(Tc=25[°]C,unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Maximum Instantaneous		$I_F = 30A$	-	1.01	1.15	V
Forward Voltage	V _F	I _F = 30A, T _C = 150 °C	-	-	0.95	V
		I _F = 40A	-	1.15	1.3	V
Maximum Instantaneous	I _R	V _R = 300V	-	-	5	uA
Reverse		V _R = 300V, T _C = 150°C	-	-	1	mA
Maximum Reverse	t _{rr}	V _R =30V IF=1A -dI/dt=50A/us	-	33	45	ns
Recovery Time						
Total capacitance	C _{tot}	V _R =0V f=1MHz	-	500	-	pF
DC Blocking Voltage	V_{BR}	I _R =100uA	310	350	-	V

DEFINITIONS

VF = Instantaneous forward voltage (pw = 300µs, D = 2%).

IR = Instantaneous reverse current.

 $R\theta JC$ = Thermal resistance junction to case.

pw = pulse width.

D = duty cycle.

5 Typical characteristics diagrams

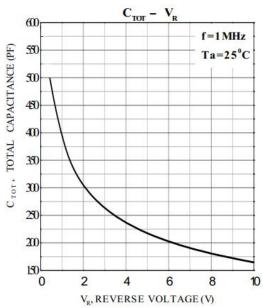


FIGURE 1. Total capacitance vs Voltage

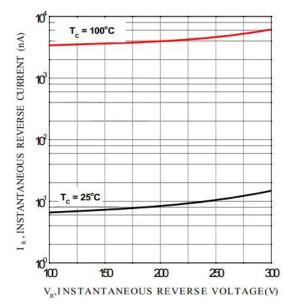


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE



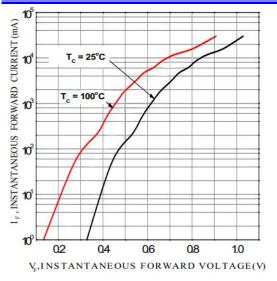


FIGURE 3. FORWARD CURRENT vs FORWARD VOLTAGE

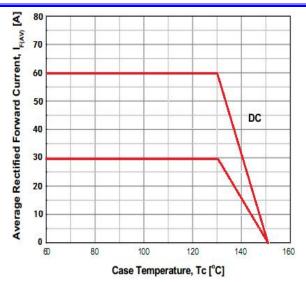


FIGURE 4. CURRENT DERATING CURVE

6 Typical Test Circuit and Waveform

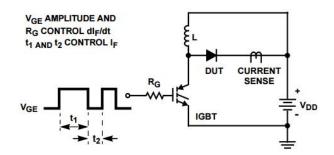


FIGURE 5. trr TEST CIRCUIT

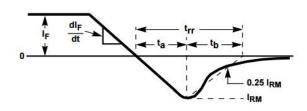


FIGURE 6. trr WAVEFORMS AND DEFINITIONS

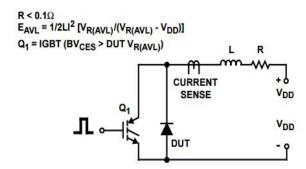


FIGURE 7. AVALANCHE ENERGY TEST CIRCUIT FIGURE

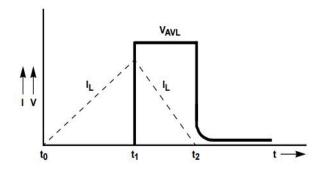
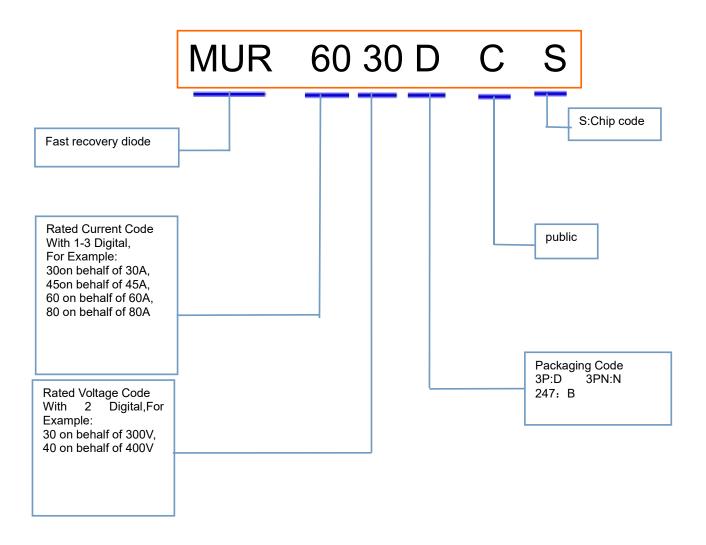


FIGURE8. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS



7 Product Names Rules



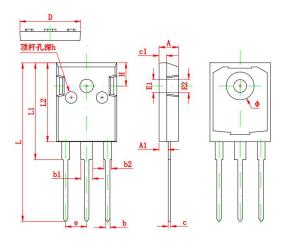
8 Product Specifications and Packaging Models

Product Model	Package Type	Mark Name	RoHS	Package	Quantity
MUR6030DCS	TO-3P	MUR6030DCS	Pb-free	Tube	300/box
MUR6030NCS	TO-3PN	MUR6030NCS	Pb-free	Tube	300/box
MUR6030BCS	TO-247	MUR6030BCS	Pb-free	Tube	300/box



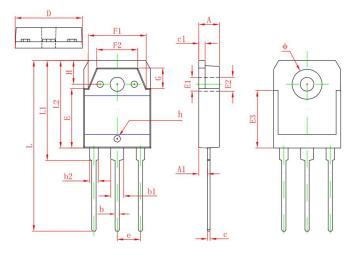
9 Dimensions

TO-247 PACKAGE OUTLINE DIMENSIONS



Complete	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min	Max	Min	Max	
Α	4.850	5.150	0.191	0.200	
A1	2.200	2.600	0.087	0.102	
b	1.000	1.400	0.039	0.055	
b1	2.800	3.200	0.110	0.126	
b2	1.800	2.200	0.071	0.087	
С	0.500	0.700	0.020	0.028	
c1	1.900	2.100	0.075	0.083	
D	15.450	15.750	0.608	0.620	
E1	3.500	3.500 REF		0.138 REF	
E2	3.600	REF	0.142 REF		
L	40.900	41.300	1.610	1.626	
L1	24.800	25.100	0.976	0.988	
L2	20.300	20.600	0.799	0.811	
Ф	7.100	7.300	0.280	0.287	
е	5.450 TYP		0.21	5 TYP	
Н	5.980 REF		0.235 REF		
h	0.000	0.300	0.000	0.012	

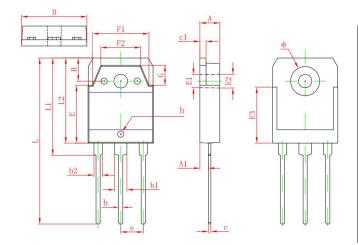
TO-3P PACKAGE OUTLINE DIMENSIONS



Cumbal	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min	Max	Min	Max	
Α	4.600	5.000	0.181	0.197	
A 1	1.200	1.600	0.047	0.063	
b	0.800	1.200	0.031	0.047	
b 1	2.800	3.200	0.110	0.126	
b 2	1.800	2.200	0.071	0.087	
С	0.500	0.700	0.020	0.028	
c 1	1.450	1.650	0.057	0.065	
D	15.450	15.850	0.608	0.624	
E	13.700	14.100	0.539	0.555	
E 1	3.200 REF		0.126 REF		
E 2	3.300	REF	0.130 REF		
E 3	13.450	REF	0.53	0.530 REF	
F 1	13.400	13.800	0.528	0.543	
F 2	9.400	9.800	0.370	0.386	
L	39.900	40.300	1.571	1.587	
L1	23.200	23.600	0.913	0.929	
L2	20.300	20.600	0.799	0.811	
Φ	6.900	7.100	0.272	0.280	
G	5.150	5.550	0.203	0.219	
е	5.450 TYP		0.21	5 TYP	
Н	5.000	REF	0.19	7 REF	
h	0.000	0.300	0.000	0.012	



TO-3PN PACKAGE OUTLINE DIMENSIONS



0	Dimensions In Millimeters		Dimension	s In Inches
Symbol	M in	Max	Min	Max
Α	4.600	5.000	0.181	0.197
A 1	2.200	2.600	0.087	0.102
b	0.800	1.200	0.031	0.047
b 1	2.800	3.200	0.110	0.126
b 2	1.800	2.200	0.071	0.087
С	0.500	0.700	0.020	0.028
c1	1.450	1.650	0.057	0.065
D	15.450	15.850	0.608	0.624
E	13.700	14.100	0.539	0.555
E 1	3.200 REF		0.126 REF	
E 2	3.300	REF	0.130 REF	
E 3	13.450	REF	0.530 REF	
F 1	13.400	13.800	0.528	0.543
F 2	9.400	9.800	0.370	0.386
L	39.900	40.300	1.571	1.587
L1	23.200	23.600	0.913	0.929
L 2	20.300	20.600	0.799	0.811
Φ	6.900	7.100	0.272	0.280
G	5.150	5.550	0.203	0.219
е	5.450 TYP		0.215 TYP	
Н	5.000	REF	0.197	REF
h	0.000	0.300	0.000	0.012

10 Attentions

- Jiangsu Donghai Semiconductor Technology Co., Ltd. reserves the right to change the specification without prior notice! The customer should obtain the latest version of the information before making the order and verify that the information is complete and up to date.
- It is the responsibility of the purchaser for any failure or failure of any semiconductor product under certain conditions. It is the responsibility of the purchaser to comply with safety standards and to take safety measures in the system design and machine manufacturing of WXDH products in order to avoid potential risk of failure. Injury or property damage.
- Product promotion is endless, our company will be dedicated to provide customers with better products.

11 Appendix

Revision history:





Date	REV.	Description	Page
2017.09.2	1.0	Original	
2018.10.8	1.1	Add to appearance	7 page